TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74HCT574AP,TC74HCT574AF

## Octal D-Type Flip-Flop with 3-State Output

The TC74HCT574A is a high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate  $\rm C^2MOS$  technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

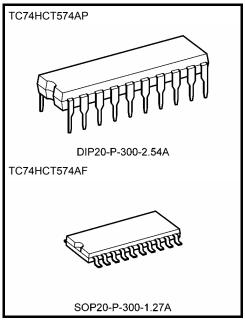
Its inputs are compatible with TTL, NMOS, and CMOS output voltage levels.

Its 8-bit D-type flip-flops is controlled by a clock input (CK) and an output enable input ( $\overline{OE}$ ).

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **Features**

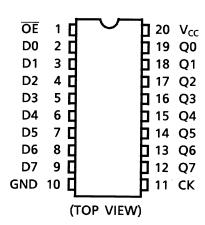
- High speed:  $f_{max} = 62 \text{ MHz}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max)}$  at  $T_{a} = 25 \text{°C}$
- Compatible with TTL outputs: V  $_{IL}$  = 0.8 V (min)  $V_{IH}$  = 2.0 V (max)
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 6 \text{ mA (min)}$
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74LS574



Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.)

#### **Pin Assignment**



# **IEC Logic Symbol**

OE (1) CK (11)	EN C1		
D0 (2) (3) (4) (5) (5) (6) (7) (8) (9) D7	1D	D ♥	(19) Q0 (18) Q1 (17) Q2 (16) Q3 (15) Q4 (14) Q5 (13) Q6 (12) Q7

## **Truth Table**

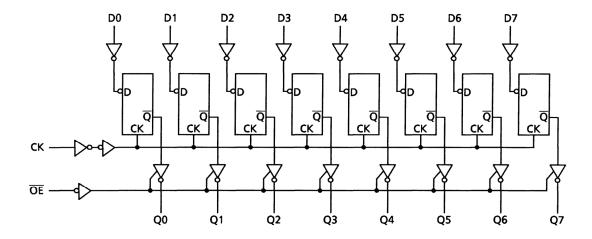
	Output		
ŌĒ	CK	D	Q
Н	Х	Х	Z
L	$\rightarrow$	Х	Qn
L		L	L
L		Н	Н

X: Don't care

Z: High impedance

Q<sub>n</sub>: No change

## **System Diagram**



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# <u>TOSHIBA</u>

### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5~7	V
DC input voltage	V <sub>IN</sub>	-0.5~V <sub>CC</sub> + 0.5	V
DC output voltage	Vout	-0.5~V <sub>CC</sub> + 0.5	V
Input diode current	l <sub>IK</sub>	±20	mA
Output diode current	lok	±20	mA
DC output current	Гоит	±35	mA
DC V <sub>CC</sub> /ground current	Icc	±75	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to  $65^{\circ}C$ . From Ta = 65 to  $85^{\circ}C$  a derating factor of -10 mW/°C shall be applied until 300 mW.

#### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5~5.5	V
Input voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0~500	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol		Test Condition		-	Га = 25°0		Ta = -40~85°C		Unit	
Characteristics	Symbol	V <sub>(</sub>		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
High-level input voltage	V <sub>IH</sub>	_		4.5~5.5	2.0	_	_	2.0	_	V
Low-level input voltage	V <sub>IL</sub>		_		_	_	0.8	_	0.8	٧
High-level output	Vou	V <sub>IN</sub>	$I_{OH} = -20 \mu A$	4.5	4.4	4.5		4.4	_	V
voltage VOH	= V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -6 mA	4.5	4.18	4.31	_	4.13	_	v	
Low-level output	V <sub>OL</sub>	V <sub>IN</sub>	$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1		0.1	V
voltage	VOL	= V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 6 mA	4.5	_	0.17	0.26	_	0.33	v
3-state output off-state current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.5	_	±5.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μА
Quiescent supply		$V_{IN} = V_{CC}$ or GND 5		5.5	_		4.0		40.0	μΑ
current	IC	Per input: V <sub>II</sub> Other input:	$_{N}$ = 0.5 V or 2.4 V $_{CC}$ or GND	5.5		_	2.0	_	2.9	mA

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### Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 ~85°C	Unit
			V <sub>CC</sub> (V)	Тур.	Limit	Limit	
Minimum pulse width	t <sub>W (H)</sub>		4.5	_	15	19	no
(CK)	t <sub>W (L)</sub>	_	5.5	_	14	17	ns
Minimum set-up time			4.5	_	15	19	
(Dn)	t <sub>s</sub>	_	5.5	_	14	17	ns
Minimum hold time			4.5	_	0	0	
(Dn)	t <sub>h</sub>	_	5.5	_	0	0	ns
Ola ala faranzana	f		4.5	_	31	25	MHz
Clock frequency	ock frequency f	_	5.5	_	34	27	IVI□Z

#### AC Characteristics (input: $t_r = t_f = 6$ ns)

Characteristics Symbol		Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol		CL (pF)	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	OTIL
Output transition time	t <sub>TLH</sub>		50	4.5	_	7	12	_	15	
Output transition time	t <sub>THL</sub>		30	5.5		6	11	_	14	ns
			50	4.5		19	30	_	38	
Propagation delay time	$t_{pLH}$		30	5.5		16	27	_	34	ns
(CK-Q)	$t_{pHL}$		150	4.5	_	24	40	_	48	115
,			150	5.5		21	35	_	44	
			50	4.5		19	30	_	38	
Output enable time	$t_{pZL}$	$R_L = 1 \text{ k}\Omega$	50	5.5	_	16	27	_	34	20
Output enable time	$t_{pZH}$		150	4.5	_	24	40	_	48	ns
			150	5.5	_	21	35	_	44	
Output disable time	$t_{pLZ}$	$R_L = 1 k\Omega$	50	4.5		19	30	_	38	ns
Output disable time	$t_{pHZ}$	K[ = 1 K22	30	5.5	_	16	27	_	34	115
Maximum clock	£		50	4.5	31	50	_	25	_	MHz
frequency	f <sub>max</sub>		30	5.5	34	60	_	27	_	IVITZ
Input capacitance	C <sub>IN</sub>		-		_	5	10	_	10	pF
Output capacitance	C <sub>OUT</sub>	_	_		_	10	_	_	_	pF
Power dissipation	C <sub>PD</sub>					62				pF
capacitance	(Note)		_			02				Ы

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

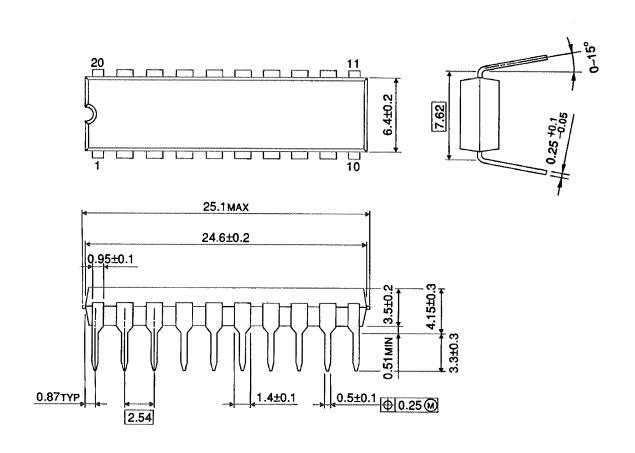
$$I_{CC}$$
 (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$  (per bit)

And the total CPD when n pcs. of flip flop operate can be gained by the following equation:

$$C_{PD}$$
 (total) = 47 + 15 · n

## **Package Dimensions**

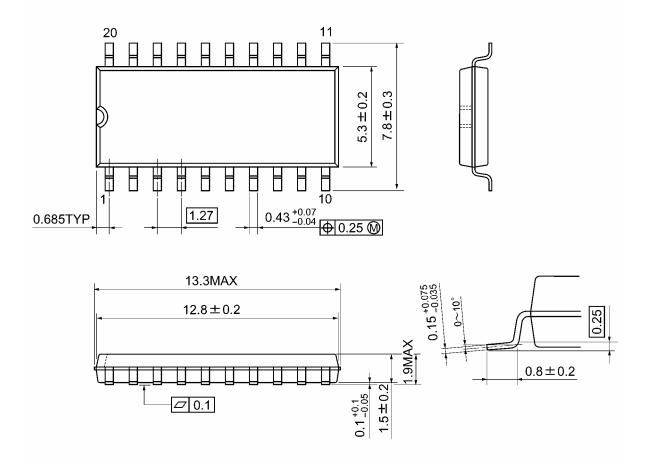
DIP20-P-300-2.54A Unit: mm



Weight: 1.30 g (typ.)

## **Package Dimensions**

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

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20070701-EN GENERAL

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